# PIP3101-A

#### DESCRIPTION

Monolithic logic level protected power MOSFET using **TOPFET2** technology assembled in a 5 pin surface mounting plastic package.

### **APPLICATIONS**

General purpose switch for driving

- lampsmotors
- motors
  solenoids
- solenoid
   heaters
- Treaters

## FEATURES

• TrenchMOS output stage with low on-state resistance

- Separate input pin for higher frequency drive
- 5 V logic compatible input
- Separate supply pin for logic and protection circuits with low operating current
- Overtemperature protection
- Drain current limiting
- Short circuit load protection
- Latched overload trip state reset
- by the protection pin

 Diagnostic flag pin indicates protection supply connected, overtemperature condition,overload tripped state, or open circuit load (detected in the off-state)

- ESD protection on all pins
- Overvoltage clamping

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
$\begin{matrix} V_{DS} \\ I_D \\ P_{tot} \\ T_j \\ R_{DS(ON)} \end{matrix}$	Continuous drain source voltage Continuous drain current Total power dissipation Continuous junction temperature Drain-source on-state resistance	50 30 90 150 28	V A W °C mΩ
SYMBOL	PARAMETER	NOM.	UNIT
V <sub>PS</sub>	Protection supply voltage	5	V

### FUNCTIONAL BLOCK DIAGRAM



#### **PIN CONFIGURATION**

mb

MBL267

mb

12345

Front view

#### SYMBOL



#### PINNING - SOT263B-01

FININING - 301203B-01					
PIN	DESCRIPTION				
1	input				
2	flag				
3	drain				
4	protection supply				
5	source				
mb	drain				



Fig. 2.

#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
	Continuous voltage				
$V_{\text{DS}}$	Drain source voltage <sup>1</sup>	$V_{IS} = 0 V$	-	50	V
	Continuous currents				
I <sub>D</sub>	Drain current	$V_{PS} = 5 \text{ V}; \text{ T}_{mb} = 25^{\circ}\text{C}$	-	self - limited	A
l <sub>i</sub> I <sub>F</sub> I <sub>P</sub>	Input current Flag current Protection supply current	$V_{PS} = 0 V; T_{mb} = 85^{\circ}C$	- -5 -5 -5	30 5 5 5 5	A mA mA mA
	Thermal				
P <sub>tot</sub>	Total power dissipation	$T_{mb} = 25^{\circ}C$	-	90	W
T <sub>stg</sub> Tj T <sub>sold</sub>	Storage temperature Junction temperature <sup>2</sup> Mounting base temperature	continuous during soldering	-55 - -	175 150 260	Û Û Û

#### ESD LIMITING VALUE

SYMBOL	PARAMETER CONDITIONS		MIN.	MAX.	UNIT
V <sub>c</sub>	5 1	Human body model; C = 250 pF; R = 1.5 k $\Omega$	-	2	kV

#### **OVERLOAD PROTECTION LIMITING VALUE**

With an adequate protection supply connected, TOPFET can protect itself from two types of overload overtemperature and short circuit load. For overload conditions an n-MOS transistor turns on between the input and source to quickly discharge the power MOSFET gate capacitance.

The drain current is limited to reduce dissipation in case of short circuit load. Refer to OVERLOAD CHARACTERISTICS.

SYMBOL	PARAMETER	REQUIRED CONDITION	MIN.	MAX.	UNIT
	Overload protection <sup>3</sup>	protection supply			
V <sub>DS</sub>	Drain source voltage	$V_{PS} \ge 4 V$	0	35	V

#### **OVERVOLTAGE CLAMPING LIMITING VALUES**

At a drain source voltage above 50 V the power MOSFET is actively turned on to clamp overvoltage transients.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
	Inductive load turn off	$I_{\text{DM}} = 20 \text{ A};  V_{\text{DD}} \leq 20 \text{ V}$			
E <sub>DSM</sub>	Non-repetitive clamping energy	$T_{mb} = 25^{\circ}C$	-	350	mJ
E <sub>DRM</sub>	Repetitive clamping energy	$T_{mb} \le 95^{\circ}C; f = 250 Hz$	-	45	mJ

<sup>1</sup> Prior to the onset of overvoltage clamping. For voltages above this value, safe operation is limited by the overvoltage clamping energy.

**<sup>2</sup>** A higher  $T_j$  is allowed as an overload condition but at the threshold  $T_{j(TO)}$  the over temperature trip operates to protect the switch.

<sup>3</sup> All control logic and protection functions are disabled during conduction of the source drain diode. If the protection circuit was previously latched, it would be reset by this condition.

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## THERMAL CHARACTERISTIC

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Thermal resistance					
R <sub>th j-mb</sub>	Junction to mounting base	-	-	1.2	1.39	K/W

#### **OUTPUT CHARACTERISTICS**

Limits are for -40°C  $\leq$  T<sub>mb</sub>  $\leq$  150°C; typicals are for T<sub>mb</sub> = 25°C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Off-state	$V_{IS} = 0 V$				
V <sub>(CL)DSS</sub>	Drain-source clamping voltage	$I_{D} = 10 \text{ mA}$	50	-	70	V
		$I_{\text{DM}}$ = 4 A; tp $\leq$ 300 $\mu$ s; $\delta \leq$ 0.01	50	60	70	V
I <sub>DSS</sub>	Drain source leakage current <sup>1</sup>	$V_{PS} = 0 \text{ V}; V_{DS} = 40 \text{ V}$ $T_{mb} = 25^{\circ}\text{C}$	-	- 0.1	100 10	μΑ μΑ
	On-state	$t_p \le 300 \ \mu s; \ \delta \le 0.01; \ V_{PS} \ge 4 \ V$				
R <sub>DS(ON)</sub>	Drain-source resistance	$I_{DM} = 10 \text{ A}; V_{IS} \ge 4.4 \text{ V}$	-	-	50	mΩ
		$T_{mb} = 25^{\circ}C$	-	21	28	mΩ

#### **INPUT CHARACTERISTICS**

Limits are for -40°C  $\leq$  T<sub>mb</sub>  $\leq$  150°C; typicals are for T<sub>mb</sub> = 25°C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Normal operation					
$V_{IS(TO)}$	Input threshold voltage <sup>2</sup>	$I_{D} = 1 \text{ mA}$ $T_{mb} = 25^{\circ}\text{C}$	0.6 1.1	- 1.6	2.6 2.1	V V
I <sub>IS</sub>	Input current	$V_{IS} = 5 V$	-	16	100	μA
V <sub>(CL)IS</sub>	Input clamping voltage	I <sub>1</sub> = 1 mA	5.5	6.4	8.5	V
R <sub>IG</sub>	Internal series resistance <sup>3</sup>	to gate of power MOSFET	-	1.7	-	kΩ
	Overload protection latched	$V_{PS} \ge 4 V$				
I <sub>ISL</sub>	Input current	$V_{IS} = 5 V$	1	2.7	4	mA

<sup>1</sup> The drain current required for open circuit load detection is switched off when there is no protection supply, in order to ensure a low off-state quiescent current. Refer to OPEN CIRCUIT LOAD DETECTION CHARACTERISTICS.

<sup>2</sup> The measurement method is simplified if  $V_{PS} = 0$  V, in order to distinguish  $I_D$  from  $I_{DSP}$ . Refer to OPEN CIRCUIT LOAD DETECTION CHARACTERISTICS.

 $<sup>{\</sup>bf 3}$  This is not a directly measurable parameter.

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## PROTECTION SUPPLY CHARACTERISTICS

Limits are for -40  $^{\circ}C \leq T_{mb} \leq 150 \,^{\circ}C;$  typicals are for  $T_{mb}$  = 25  $^{\circ}C.$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Protection & detection					
$V_{PSF}$	Threshold voltage <sup>1</sup>	$I_{F} = 100 \ \mu A; V_{DS} = 5 \ V$	2.5	3.45	4	V
I <sub>PS</sub> , I <sub>PSL</sub>	Normal operation or protection latched Supply current	V <sub>PS</sub> = 4.5 V	-	210	450	μΑ
$V_{(CL)PS}$	Clamping voltage	I <sub>P</sub> = 1.5 mA	5.5	6.5	8.5	V
	Overload protection latched					
V <sub>PSR</sub> t <sub>pr</sub>	Reset voltage Reset time	$V_{PS} \leq 1 V$	1 10	1.8 45	3 120	V μs

### **OPEN CIRCUIT LOAD DETECTION CHARACTERISTICS**

An open circuit load condition can be detected while the TOPFET is in the off-state. Refer to TRUTH TABLE.  $V_{PS} = 5 \text{ V}$ . Limits are for -40°C  $\leq T_{mb} \leq 150$ °C and typicals are for  $T_{mb} = 25$ °C.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>DSP</sub>	Off-state drain current <sup>2</sup>	$V_{IS} = 0 \text{ V}; 2 \text{ V} \leq V_{DS} \leq 40 \text{ V}$	0.9	1.8	2.7	mA
V <sub>DSF</sub>	Drain threshold voltage <sup>3</sup>	$V_{IS} = 0 V$	0.2	1	2	V
V <sub>ISF</sub>	Input threshold voltage4	I <sub>D</sub> = 100 μA	0.3	0.8	1.1	V

### **OVERLOAD CHARACTERISTICS**

#### T<sub>mb</sub> = 25°C unless otherwise specified. SYMBOL CONDITIONS TYP. UNIT PARAMETER MIN. MAX. $V_{PS} > 4 V$ Short circuit load $I_{D}$ Drain current limiting $V_{IS} = 5 V;$ $-40^{\circ}C \leq T_{mb} \leq 150^{\circ}C$ 28.5 44 60 А $V_{PS} > 4 V$ **Overload protection** 250 P<sub>D(TO)</sub> Overload power threshold device trips if $P_D > P_{D(TO)}$ 75 185 W Characteristic time which determines trip time<sup>5</sup> 250 380 600 T<sub>DSC</sub> μs $V_{PS} = 5 V$ **Overtemperature protection** from $I_D \ge 4$ A or $V_{DS} > 0.2$ V °C $\mathsf{T}_{j(\mathsf{TO})}$ Threshold temperature 150 170 \_

<sup>1</sup> When  $V_{PS}$  is less than  $V_{PSF}$  the flag pin indicates low protection supply voltage. Refer to TRUTH TABLE.

<sup>2</sup> The drain source current which flows in a normal load when the protection supply is high and the input is low.

**<sup>3</sup>** If  $V_{DS} < V_{DSF}$  then the flag indicates open circuit load.

**<sup>4</sup>** For open circuit load detection,  $V_{IS}$  must be less than  $V_{ISF}$ .

**<sup>5</sup>** Trip time  $t_{d sc}$  varies with overload dissipation  $P_D$  according to the formula  $t_{d sc} \approx T_{DSC} / ln[P_D / P_{D(TO)}]$ .

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## **TRUTH TABLE**

For normal, open-circuit load and overload conditions or inadequate protection supply voltage. Assumes proper external pull-up for flag pin. Refer to FLAG CHARACTERISTICS.

PROTECTION	INPUT	FLAG	OUTPUT
1	1	0	ON
1	0	0	OFF
1	1	0	ON
1	0	1	OFF
1	1	1	OFF
1	Х	1	OFF
0	1	1	ON
0	0	1	OFF
	1 1 1 1 1 1 1 0	1     1       1     0       1     1       1     0       1     1       1     X       0     1	1     1     0       1     0     0       1     1     0       1     0     1       1     1     1       1     X     1       0     1     1

**KEY** '0' equals low '1' equals high 'X' equals don't care.

# **FLAG CHARACTERISTICS**

The flag is an open drain transistor which requires an external pull-up circuit. Limits are for -40°C  $\leq T_{mb} \leq 150$ °C; typicals are for  $T_{mb} = 25$ °C.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	Flag 'low'	normal operation; $V_{PS} = 5 V$				
V <sub>FSF</sub>	Flag voltage	I <sub>F</sub> = 100 μA	-	0.8	1	V
I <sub>FSF</sub>	Flag saturation current	$V_{FS} = 5 V$	-	10	-	mA
	Flag 'high'	overload or fault				
I <sub>FSO</sub>	Flag leakage current	$V_{FS} = 5 V$	-	0.1	10	μA
V <sub>(CL)FS</sub>	Flag clamping voltage	I <sub>F</sub> = 100 μA	5.5	6.2	8.5	V
	Application information					
R <sub>F</sub>	Suitable external pull-up resistance	$V_{FF} = 5 V$	-	47	-	kΩ

### SWITCHING CHARACTERISTICS

 $T_{\text{mb}} = 25^{\circ}\text{C}; \ \text{R}_{\text{I}} = 50 \ \Omega; \text{R}_{\text{IS}} = 50 \ \Omega; \text{V}_{\text{DD}} = 15 \text{ V}; \text{ resistive load } \text{R}_{\text{L}} = 10 \ \Omega.$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
t <sub>d on</sub>	Turn-on delay time	$V_{IS}: 0 V \Rightarrow 5 V$	-	1.8	5	μs
t <sub>r</sub>	Rise time		-	3.5	8	μs
t <sub>d off</sub>	Turn-off delay time $V_{IS}$ : 5 V $\Rightarrow$ 0 V		-	11	30	μs
t <sub>f</sub>	Fall time		-	5	12	μs

<sup>1</sup> In this condition the protection circuit is latched. To reset the latch the protection pin must be taken low. Refer to PROTECTION SUPPLY CHARACTERISTICS.

#### **Product Specification**

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## CAPACITANCES

 $T_{mb} = 25 \degree C; f = 1 \text{ MHz}$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
C <sub>iss</sub>	Input capacitance	$V_{DS} = 25 \text{ V}; V_{IS} = 0 \text{ V}$	-	710	1050	pF
C <sub>oss</sub> Output capacitance		$V_{DS} = 25 \text{ V}; V_{IS} = 0 \text{ V}$	-	370	550	pF
C <sub>rss</sub>	Reverse transfer capacitance	$V_{DS} = 25 \text{ V}; V_{IS} = 0 \text{ V}$	-	26	40	pF
$C_{pso}$	Protection supply pin capacitance	$V_{PS} = 5 V$	-	22	-	рF
$C_{fso}$	Flag pin capacitance	$V_{FS} = 5 V; V_{PS} = 0 V$	-	12	-	pF





















### **MECHANICAL DATA**



<sup>1</sup> Refer to mounting instructions for TO220 envelopes. Epoxy meets UL94 VO at 1/8". Net mass: 2 g

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#### DEFINITIONS

DATA SHEET STATUS				
DATA SHEETPRODUCTSTATUS1STATUS2		DEFINITIONS		
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice		
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product		
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A		

#### Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### Application information

Where application information is given, it is advisory and does not form part of the specification.

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